Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

Between 0.120 inches and 0.200 inches

Terminal Length:

Between 1.000 inches and 1.500 inches

Overall Diameter:

Between 0.055 inches and 0.090 inches

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

720.0 nonrepetitive peak reverse voltage and 600.0 working peak reverse voltage

Current Rating Per Characteristic:

5.00 amperes forward current, average preset and 400.00 milliamperes forward current, total rms megahertz

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

2 uninsulated wire lead

Specification Data:

81349-mil-s-19500/240 government specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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